

# Dong-Ming Sun

## List of Publications by Year in descending order

Source: <https://exaly.com/author-pdf/7924434/publications.pdf>

Version: 2024-02-01

47  
papers

4,339  
citations

201674

27  
h-index

233421

45  
g-index

47  
all docs

47  
docs citations

47  
times ranked

6751  
citing authors

#	ARTICLE	IF	CITATIONS
1	High-Purity Monochiral Carbon Nanotubes with a 1.2Ånm Diameter for High-Performance Field-Effect Transistors. <i>Advanced Functional Materials</i> , 2022, 32, 2107119.	14.9	16
2	Laminated three-dimensional carbon nanotube integrated circuits. <i>Nanoscale</i> , 2022, 14, 7049-7054.	5.6	1
3	Patterning of Wafer-Scale MXene Films for High-Performance Image Sensor Arrays. <i>Advanced Materials</i> , 2022, 34, e2201298.	21.0	26
4	A monolithically sculpted van der Waals nano-opto-electro-mechanical coupler. <i>Light: Science and Applications</i> , 2022, 11, 48.	16.6	7
5	A photon-controlled diode with a new signal-processing behavior. <i>National Science Review</i> , 2022, 9, .	9.5	2
6	Fermi-Level Depinning in Metal/Ge Junctions by Inserting a Carbon Nanotube Layer. <i>Small</i> , 2022, 18, e2201840.	10.0	5
7	High-performance gold/graphene/germanium photodetector based on a graphene-on-germanium wafer. <i>Nanotechnology</i> , 2022, 33, 345204.	2.6	4
8	Key factors for ultra-high on/off ratio thin-film transistors using as-grown carbon nanotube networks. <i>RSC Advances</i> , 2022, 12, 16291-16295.	3.6	5
9	Engineering Graphene Grain Boundaries for Plasmonic Multi-Excitation and Hotspots. <i>ACS Nano</i> , 2022, 16, 9041-9048.	14.6	7
10	Preparation of isolated semiconducting single-wall carbon nanotubes by oxygen-assisted floating catalyst chemical vapor deposition. <i>Chemical Engineering Journal</i> , 2022, 450, 137861.	12.7	7
11	High-performance flexible resistive random access memory devices based on graphene oxidized with a perpendicular oxidation gradient. <i>Nanoscale</i> , 2021, 13, 2448-2455.	5.6	12
12	A flexible ultrasensitive optoelectronic sensor array for neuromorphic vision systems. <i>Nature Communications</i> , 2021, 12, 1798.	12.8	198
13	Properties and photodetector applications of two-dimensional black arsenic phosphorus and black phosphorus. <i>Science China Information Sciences</i> , 2021, 64, 1.	4.3	35
14	Small-Hysteresis Flexible Carbon Nanotube Thin-Film Transistors using Stacked Architecture. , 2021, , .		0
15	An ultrasensitive molybdenum-based double-heterojunction phototransistor. <i>Nature Communications</i> , 2021, 12, 4094.	12.8	37
16	A flexible nickel phthalocyanine resistive random access memory with multi-level data storage capability. <i>Journal of Materials Science and Technology</i> , 2021, 86, 151-157.	10.7	18
17	Pushing the conductance and transparency limit of monolayer graphene electrodes for flexible organic light-emitting diodes. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2020, 117, 25991-25998.	7.1	28
18	Chemical vapor deposition of layered two-dimensional MoSi <sub>2</sub> N <sub>4</sub> materials. <i>Science</i> , 2020, 369, 670-674.	12.6	556

#	ARTICLE	IF	CITATIONS
19	A FinFET with one atomic layer channel. <i>Nature Communications</i> , 2020, 11, 1205.	12.8	83
20	A Flexible Carbon Nanotube Senâ€Memory Device. <i>Advanced Materials</i> , 2020, 32, e1907288.	21.0	48
21	A Graphene Base Transistor for Potential Terahertz Application. , 2020, , .		0
22	Ultrafast growth of nanocrystalline graphene films by quenching and grain-size-dependent strength and bandgap opening. <i>Nature Communications</i> , 2019, 10, 4854.	12.8	43
23	A vertical silicon-graphene-germanium transistor. <i>Nature Communications</i> , 2019, 10, 4873.	12.8	37
24	Gate tunable giant anisotropic resistance in ultra-thin GaTe. <i>Nature Communications</i> , 2019, 10, 2302.	12.8	72
25	Interlayer epitaxy of wafer-scale high-quality uniform AB-stacked bilayer graphene films on liquid Pt <sub>3</sub> Si/solid Pt. <i>Nature Communications</i> , 2019, 10, 2809.	12.8	43
26	A Double Support Layer for Facile Clean Transfer of Two-Dimensional Materials for High-Performance Electronic and Optoelectronic Devices. <i>ACS Nano</i> , 2019, 13, 5513-5522.	14.6	29
27	Flexible 64 Å— 64 Pixel AMOLED Displays Driven by Uniform Carbon Nanotube Thin-Film Transistors. <i>ACS Applied Materials &amp; Interfaces</i> , 2019, 11, 11699-11705.	8.0	33
28	Flexible layer-structured Bi <sub>2</sub> Te <sub>3</sub> thermoelectric on a carbon nanotube scaffold. <i>Nature Materials</i> , 2019, 18, 62-68.	27.5	316
29	Highâ€Throughput Fabrication of Flexible and Transparent Allâ€Carbon Nanotube Electronics. <i>Advanced Science</i> , 2018, 5, 1700965.	11.2	34
30	Ultrahigh-performance transparent conductive films of carbon-welded isolated single-wall carbon nanotubes. <i>Science Advances</i> , 2018, 4, eaap9264.	10.3	178
31	High Sensitivity Photonic Crystal Fiber Refractive Index Sensor with Gold Coated Externally Based on Surface Plasmon Resonance. <i>Micromachines</i> , 2018, 9, 640.	2.9	35
32	UV-Epoxy-Enabled Simultaneous Intact Transfer and Highly Efficient Doping for Roll-to-Roll Production of High-Performance Graphene Films. <i>ACS Applied Materials &amp; Interfaces</i> , 2018, 10, 40756-40763.	8.0	18
33	Electric-field control of magnetism in a few-layered van der Waals ferromagnetic semiconductor. <i>Nature Nanotechnology</i> , 2018, 13, 554-559.	31.5	466
34	Continuous Fabrication of Meterâ€Scale Singleâ€Wall Carbon Nanotube Films and their Use in Flexible and Transparent Integrated Circuits. <i>Advanced Materials</i> , 2018, 30, e1802057.	21.0	63
35	Circular Graphene Platelets with Grain Size and Orientation Gradients Grown by Chemical Vapor Deposition. <i>Advanced Materials</i> , 2017, 29, 1605451.	21.0	8
36	A carbon nanotube non-volatile memory device using a photoresist gate dielectric. <i>Carbon</i> , 2017, 124, 700-707.	10.3	10

#	ARTICLE	IF	CITATIONS
37	Selective Growth of Metal-Free Metallic and Semiconducting Single-Wall Carbon Nanotubes. <i>Advanced Materials</i> , 2017, 29, 1605719.	21.0	21
38	Ultrafast Growth of High-Quality Monolayer $WSe_2$ on Au. <i>Advanced Materials</i> , 2017, 29, 1700990.	21.0	139
39	Gate-controlled reversible rectifying behaviour in tunnel contacted atomically-thin $MoS_2$ transistor. <i>Nature Communications</i> , 2017, 8, 970.	12.8	68
40	All-Carbon Thin-Film Transistors as a Step Towards Flexible and Transparent Electronics. <i>Advanced Electronic Materials</i> , 2016, 2, 1600229.	5.1	32
41	Growth of semiconducting single-wall carbon nanotubes with a narrow band-gap distribution. <i>Nature Communications</i> , 2016, 7, 11160.	12.8	75
42	Large-area synthesis of high-quality and uniform monolayer $WS_2$ on reusable Au foils. <i>Nature Communications</i> , 2015, 6, 8569.	12.8	336
43	Mouldable all-carbon integrated circuits. <i>Nature Communications</i> , 2013, 4, 2302.	12.8	141
44	Reduced graphene oxide with a highly restored $\pi$ -conjugated structure for inkjet printing and its use in all-carbon transistors. <i>Nano Research</i> , 2013, 6, 842-852.	10.4	68
45	A Review of Carbon Nanotube- and Graphene-Based Flexible Thin-Film Transistors. <i>Small</i> , 2013, 9, 1188-1205.	10.0	268
46	Effect of carbon nanotube network morphology on thin film transistor performance. <i>Nano Research</i> , 2012, 5, 307-319.	10.4	59
47	Flexible high-performance carbon nanotube integrated circuits. <i>Nature Nanotechnology</i> , 2011, 6, 156-161.	31.5	652